

## Supporting Information

# Enhanced hydrogen evolution reaction activity of T'-phase tungsten dichalcogenides (WS<sub>2</sub>, WSe<sub>2</sub>, and WTe<sub>2</sub>) materials by defect engineering

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Table S1. Hydrogen adsorption energy ( $E_{\text{ads}}$ ) of T'-WS<sub>2</sub>, T'-WSe<sub>2</sub> and T'-WTe<sub>2</sub> with stable various defect configurations at different adsorption positions.

	Defect	Sites	$E_{\text{ads}}$ (eV)		Defect	Sites	$E_{\text{ads}}$ (eV)		Defect	Sites	$E_{\text{ads}}$ (eV)
WS <sub>2</sub>	V1	-	-	WSe <sub>2</sub>	V1	-	-	WTe <sub>2</sub>	V1	-	-
		-	-			-	-			-	-
	V2	top-V	-3.06		V2	top-V	-3.10		V2	top-V	-2.95
		top-S1	-2.16			top-Se	-1.77			top-Te	-1.55
	DV1	-	-		DV1	-	-		DV1	-	-
		-	-			-	-			-	-
	DV2	top-V	-2.96		DV2	top-V	-3.01		DV2	top-v1	-2.91
		top-S1	-1.71			top-Se	-1.65			top-v2	-2.51
	Bs	top-B	-3.09		B <sub>Se</sub>	top-B	-3.13		B <sub>Te</sub>	top-B	-3.04
		top-S1	-2.33			top-Se	-1.84			top-Te	-1.62
	Cs	top-C	-3.14		C <sub>Se</sub>	top-C	-3.24		C <sub>Te</sub>	top-C	-3.23
		top-S2	-2.24			top-Se	-1.79			top-Te	-1.68
	Ps	top-P	-2.89		P <sub>Se</sub>	top-P	-2.78		P <sub>Te</sub>	top-P	-2.69
		top-S2	-2.20			top-Se	-1.83			top-Te	-1.68

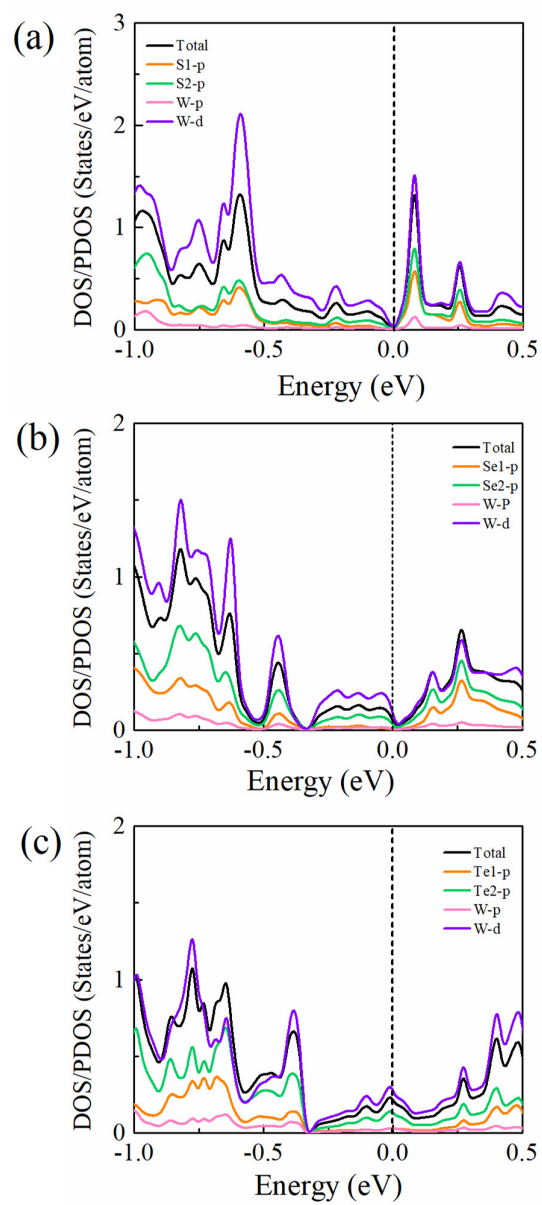


Figure S1. Electronic density of states of (a) T'-WS<sub>2</sub>, (b) T'-WSe<sub>2</sub> and (c) T'-WTe<sub>2</sub>, respectively. The vertical dot line denotes the fermi level.

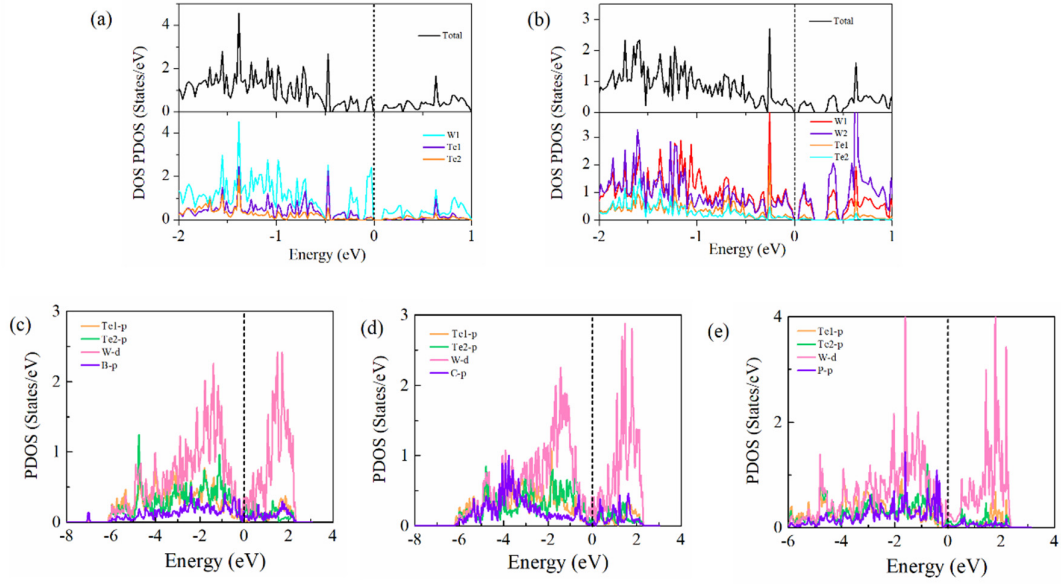


Figure S2. Density of states (DOS) and partial density of states (PDOS) of T'-WTe<sub>2</sub> monolayer with (a) single-vacancy (V), (b) double-vacancy (DV), (c) B-doping, (d) C-doping and (e) P-doping, respectively. The vertical dotted line denotes the fermi level.

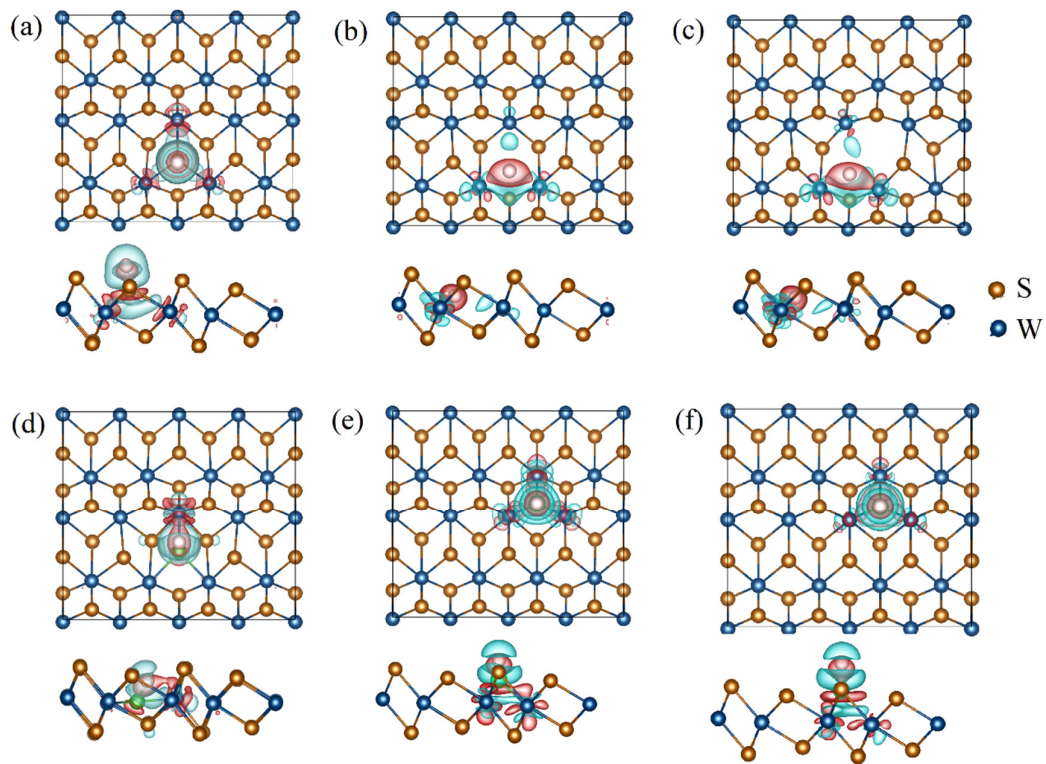


Figure S3. Difference of charge density of  $\text{WS}_2$  with H-adsorption system for (a) pristine, (b) single-vacancy, (c) double-vacancy, (d) B-doping, (e) C-doping and (f) P-doping from top and side view, respectively. Note that red color indicates charge accumulation and green color denotes charge depletion.

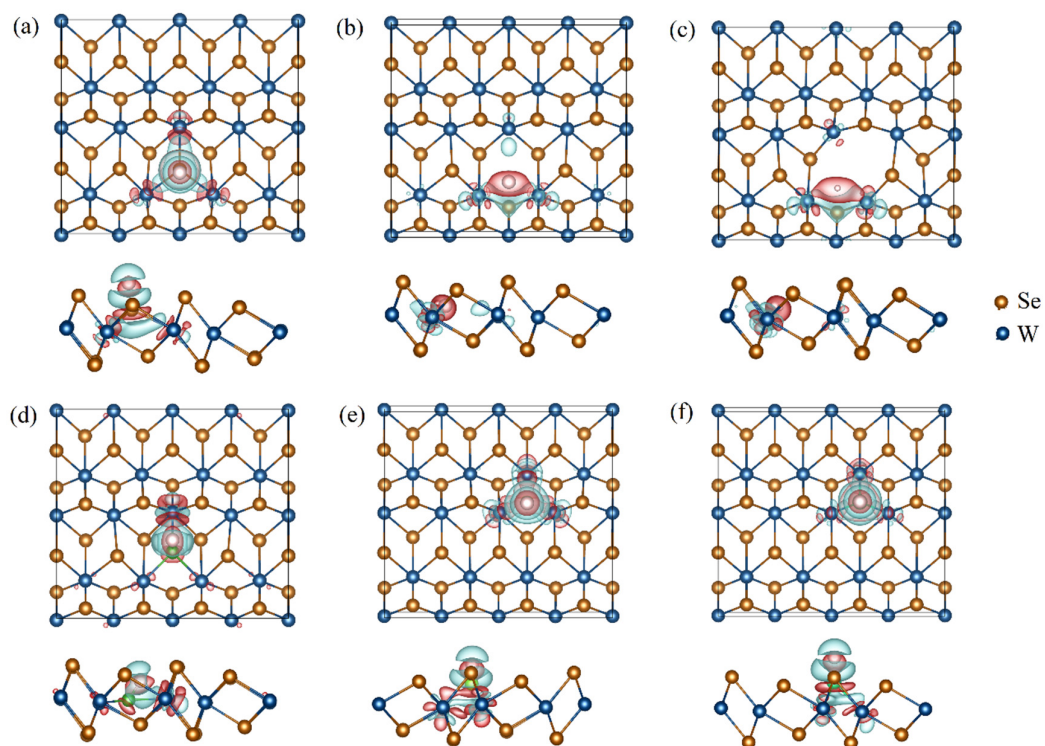


Figure S4. Difference of charge density of WSe<sub>2</sub> with H-adsorption system for (a) pristine, (b) single-vacancy, (c) double-vacancy, (d) B-doping, (e) C-doping and (f) P-doping from top and side view, respectively. Note that red color indicates charge accumulation and green color denotes charge depletion.